2SD2396

Transistor, NPN

Features

- available in TO-220FN package
- high dc current gain (h_{FE}), typically h_{FE} = 1000
- low collector saturation voltage, typically $V_{CE(sat)} = 0.3$ V at $I_C/I_B = 2$ A/ 0.05 A
- large collector power dissipation:
 P_C = 30 W at T_C = 25°C
- easily insulated from the heat sink as the fin is molded
- 2 mm lower than ROHM'S TO-220FP package which allows higher density mounting
- wide safe operating area (SOA)

Applications

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• low frequency power amplifier

Dimensions (Units : mm)

2SD2396 (TO-220FN)



Parameter	Symbol	Limits	Unit	Conditions
Collector-to-base voltage	V _{CBO}	80	V	
Collector-to-emitter voltage	V _{CEO}	60	v	
Emitter-to-base voltage	V _{EBO}	6	V	
Collector current	Ic I	3	A	Continuous (dc)
	I _{CP}	6	A	Single pulse, P _W = 100 ms
Collector dissipation		2	W	
	Pc	30	w	$T_{C} = 25^{\circ}C$
Junction temperature	T _i	150	°C	
Storage temperature	T _{stg}	-55 ~ +150	°C	

Absolute maximum ratings ($T_a = 25^{\circ}C$)

2SD2396	Transistor,	NPN,	2SD	series
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Electrical characteristics (unless oth	herwise noted, T ₂ = 25°C	
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Parameter	Symbol	Min	Typical	Max	Unit	Conditions
Collector-to-base breakdown voltage	BV _{CBO}	80			v	I _C = 50 μA
Collector-to-emitter breakdown voltage	BV _{CEO}	60			v	I _C = 1 mA
Emitter-to-base breakdown voltage	BV _{EBO}	6			v	l _E = 50 μA
Collector cutoff current	Ісво			100	μΑ	V _{CB} = 80 V
Emitter cutoff current	I _{EBO}			100	μΑ	$V_{EB} = 6 V$
DC current gain	h _{FE}	400	1000	2000		$V_{CE} = 4 V$, $I_{C} = 0.5 A$, single pulse
Collector-to-emitter saturation voltage	V _{CE(sat)}		0.3	0.8	v	$I_{\rm C}/I_{\rm B} = 2$ A/0.05 A, single pulse
Collector-to-base saturation voltage	V _{BE(sat)}			1.5	v	$I_{\rm C}/I_{\rm B} = 2$ A/0.05 A, single pulse
Transition frequency	f _T		40		MHz	$V_{CE} = 5 \text{ V}, I_E = -0.2 \text{ A}, f = 10 \text{ MHz},$ single pulse
Output capacitance	C _{ob}		55		pF	$V_{CB} = 10 \text{ V}, J_{E} = 0 \text{ A}, f = 1 \text{ MHz}$

h_{FE} rankings

ltem	Н	J	К	
h _{FE}	400 ~ 800	600 ~ 1200	1000 ~ 2000	

Electrical characteristic curves







Transistor, NPN, 2SD series 2SD2396





Ordering information

Package	Bulk
Code	
Basic order quantity	500
2SD2396	* * * * * *
★ = Standard, ☆ = Semi-sta	ndard, * = Special order

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